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Torque magnetometry of an amorphous-alumina/strontium-titanate interface

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We report torque magnetometry measurements of an oxide heterostructure consisting of an amorphous Al2O3 thin film grown on a crystalline SrTiO3 substrate (a-AO/STO) by atomic layer deposition. We find a torque response that resembles previous studies of crystalline LaAlO3/SrTiO3 (LAO/STO) heterointerfaces, consistent with strongly anisotropic magnetic ordering in the plane of the interface. Unlike crystalline LAO, amorphous Al2O3 is nonpolar, indicating that planar magnetism at an oxide interface is possible without the strong internal electric fields generated within the polarization catastrophe model. We discuss our results in the context of current theoretical efforts to explain magnetism in crystalline LAO/STO.

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The interfacial two-dimensional electron gas (2DEG) in LaAlO3/SrTiO3 (LAO/STO) heterostructures has attracted intense experimental and theoretical attention due to the hope of tailoring the properties of strongly correlated electrons via confinement [1,2]. In particular, the polar catastrophe model that is thought to underlie the existence of a conducting 2D electron gas without the two-dimensional interface may provide a path to creating confined, high carrier density electron systems without the need for chemical doping [3,4]. An amorphous Al2O3 thin film grown on a crystalline SrTiO3 substrate (a-AO/STO) provides a useful comparison system for the role of the polar catastrophe in LAO/STO: Chemically similar yet structurally distinct, the a-AO/STO interface is nonpolar. Theoretical explanations of properties common to both systems, then, should be reconciled with the absence of the strong electric fields generic to polar catastrophe models in LAO/STO.

However, the charge carrier densities are roughly one order of magnitude lower in a-AO/STO than in LAO/STO, and the charge transport can be permanently suppressed by oxygen postannealing of the amorphous samples [5,6]. These disparate observations allow a reconciliation of the apparent similarity: While it is likely that oxygen vacancy doping contributes to the charge transport in both systems, the polar electric fields in LAO/STO appear to generate a higher charge carrier density and more robust interfacial conduction.

Among the notable features of the LAO/STO interface has been the observation of magnetism [7–15]. As neither of the parent materials is magnetic, the magnetism appears to be a new property generated by the electronic confinement. Relatively little is known about the origin of the magnetism, with several distinct theoretical proposals awaiting experimental testing. These proposals fall into two categories, being based either on intrinsic properties of the 2DEG in the polar catastrophe scenario [16,17] or on (extrinsic) defect states that may or may not be related to the strong fields generated in the polar interfaces [18–20]. Here, we show that magnetism qualitatively similar to that observed in LAO/STO interfaces is also present in a-AO/STO heterostructures. Our results raise the possibility that growth defects play a large role in the observation of magnetism in LAO/STO.

Our measurement involves placing a heterostructure on the end of a brass cantilever so that the interface is parallel to the cantilever [Fig. 1(b) inset]. In the presence of an applied magnetic field \( H \) the cantilever will experience a torque \( \tau = m \times \mu_0 H \). For a moment \( m \) which is in the plane of the interface, the torque signal will be \( \tau = \mu_0 m(H) H \cos \phi \), where \( \phi \) is the angle between the applied magnetic field and the axis perpendicular to the interface [Fig. 1(a) inset]. Such a torque will deflect the cantilever, and this deflection can be detected via the change in the cantilever’s capacitance to a nearby conducting plane. We point out that torque magnetometry is directly sensitive to the magnetic moment parallel to the plane of the cantilever. Accordingly, we are sensitive to planar magnetic contributions from both the interface as well as the substrate. However, we find it unlikely that magnetic contributions far from the interface would show strong planar anisotropy. We note that torque measurements performed on bare STO substrates in Ref. [11] showed no signs of planar magnetism.

Our sample consists of amorphous alumina grown on a single crystal STO substrate using an atomic layer deposition technique described previously [5]. 5 nm of amorphous alumina were grown on a TiO2-terminated STO substrate at 300 °C using trimethylaluminum and H2O as the aluminum precursor and oxygen source, respectively. The room temperature electron density at the a-AO/STO interface was \( 3 \times 10^{12} \) cm\(^{-2} \) (determined by Hall measurement). A 100 nm thick aluminum loop was subsequently deposited around the edge of the 6 mm \( \times \) 6 mm sample [see Fig. 1(b) inset] to allow in situ calibration of the cantilever torque constant. The loop was grounded when measuring the heterostructure torque. The sample was fixed with GE varnish to a cantilever made from 25 \( \mu \)m thick brass foil. The cantilever was suspended on a glass post above a fixed brass conducting plane on a G10 chip carrier.

We measured capacitance with a 5 V excitation at 8 kHz using a General Radio 1615A capacitance bridge and lock-in amplifier. Measurements were performed with the sample immersed in liquid \(^{3}\)He (for base temperature measurements).
The torque signal monotonically decreases with increasing $H$ (range to 5 T) as arising from in-plane magnetic ordering. We restrict our deflection response, which we interpret (following Ref. [11]) monotonically increase in magnitude with the sign of the either the positive or negative direction, the torque signals of an in-plane magnetic moment. As the angle is tilted in there is a negligible torque signal, indicating the absence of no detectable hysteresis. We report data from one sample with our most complete torque series and temperature dependence. We also saw similar signs of magnetic ordering in one other nominally identical sample.

The angle between the applied field and the interface $\phi$ describes the tilt angle of the magnetic field with respect to the axis perpendicular to the interface [Fig. 1(a) inset]. For a constant in-plane moment $m(H) = m_0$, the torque signal is linear in $H$. For a more general in-plane moment $m(H)$ which evolves as a function of the applied field, the torque traces will be nonlinear at low applied field but will reach a linear regime once the in-plane moment has saturated (as in a superparamagnetic or ferromagnetic system). In addition to a possible linear signal indicative of magnetic ordering, the sample may also have an overall paramagnetic or diamagnetic background. Although torque of the form $m \times \mu_0 H$ vanishes for paramagnetic and diamagnetic contributions ($m \propto H$), the presence of small magnetic field gradients perpendicular to the plane of the cantilever results in a deflection proportional to $V(m \cdot \mu_0 H)$. For paramagnetic or diamagnetic moments ($m \propto H$) this corresponds to a deflection proportional to $H^2$. At low applied field we are dominated by the linear deflection response, which we interpret (following Ref. [11]) as arising from in-plane magnetic ordering. We restrict our range to $|\mu_0 H| < 0.5$ T to remain within this regime. (See Fig. 3 for an example of a larger field range with quadratic contributions.)

Figure 1(a) shows torque traces for small $\phi$. At $\phi \approx 0^\circ$ there is a negligible torque signal, indicating the absence of an in-plane magnetic moment. As the angle is tilted in either the positive or negative direction, the torque signals monotonically increase in magnitude with the sign of the slope determined by the tilt direction. The slope inversion about $\phi = 0^\circ$ suggests that, as in LAO/STO [11], there is either no coercive field or one that cannot be resolved with our technique, which loses sensitivity at small applied field. The increase in torque signal indicates an increase of the in-plane moment up to a maximum value which occurs between about $|\phi| \approx 10^\circ$ and $25^\circ$. At applied field $H \gtrsim 0.25$ T, the torque traces are linear, indicating a constant in-plane moment consistent with either superparamagnetism or ferromagnetism with a small coercive field which we cannot detect. We note that the size of the in-plane moment in the linear regime shows dependence on the out-of-plane field (see Fig. 2). This is consistent with a picture of the interfacial moments canting slightly out of the plane of the interface when subjected to a strong out-of-plane field. However, because our measurement is only sensitive to the in-plane field, we have no way of verifying this picture and make no claims as to the origin of this dependence. Figure 1(b) shows torque traces at larger tilt angles. After passing through a maximum at $\phi = 27^\circ$, the torque signal monotonically decreases as $\phi$ approaches $90^\circ$, where the applied field is parallel to the interface. Because $\tau \propto H_\perp$, the torque signal is strongly suppressed at large angles and vanishes completely at $\phi = 90^\circ$.

The angle between the applied field and the interface was determined by first setting the interface perpendicular to the applied magnetic field ($\phi = 0^\circ$). This was achieved by both observing a torque trace with zero amplitude as well as a maximum in the cantilever to conducting plane capacitance. Our cryogenic rotation stage was controlled by a room temperature calibrated linear actuator. By referencing the position of the linear actuator relative to $\phi = 0^\circ$ we could determine the angle of inclination of the rotation stage with respect to the applied field. However, this does not take into account the mechanical bending of the cantilever as the rotation stage changes orientation. This may cause an error in our angle.
FIG. 2. (Color online) Magnetic moment calculation. The magnetic moment $m(H)$ was calculated from the torque traces by dividing by the perpendicular applied field: $m(H) = \tau(H)/\mu_0 H \cos \theta$. The trace corresponding to $\phi = 90^\circ$ was excluded due to the loss of sensitivity around $\phi \sim 90^\circ$. Data below 50 mT have been suppressed due to loss of torque sensitivity at low field. The net magnetic moment has been expressed in units of Bohr magnetons $\mu_B$ per 2D STO unit cell (u.c.).

FIG. 3. (Color online) Temperature dependence of torque. Torque traces at constant $\phi = -11^\circ$ from 400 mK to 30 K. There is no quantitative change in torque signal below 0.5 T throughout the accessible temperature range. The curvature at the higher field is due to an overall diamagnetic background.
much larger areal moment density, our data raise the possibility that growth defects are largely responsible for magnetic ordering in both epitaxial and amorphous oxide interfaces which have not been oxygen postannealed.

In addition to considering previous torque measurements, our results may provide an important context for recent reports of interfacial magnetism in LAO/STO. We note that Ref. [15] found evidence of the absence of interfacial magnetism in oxygen postannealed LAO/STO heterostructures using x-ray absorption spectroscopy. The residual magnetism observed in oxygen annealed samples [15] was consistent with previous neutron reflectometry results [13]. However, Ref. [14] found evidence of Ti$^{3+}$ magnetism in oxygen annealed samples. It has also been recently proposed that the polarization catastrophe may generate interfacial defects which ultimately are responsible for localized magnetic moments at the interface [20]. In this scenario Ti-on-Al antisite defects are responsible for magnetism and not oxygen vacancies, as proposed elsewhere [18]. Our data do not rule out the possibility of distinct mechanisms driving qualitatively similar magnetism in epitaxial LAO/STO and $a$-AO/STO. Rather, our results point to the necessity of incorporating the role of growth related defects when describing interfacial magnetism in oxides.

There are several future measurements that could isolate which aspects of the oxide interface landscape are responsible for magnetism. Namely, performing similar torque measurements on oxygen annealed samples could demonstrate whether or not the magnetism arises from oxygen vacancies. Similarly, performing magnetometry on $a$-AO/STO structures with different overlayer thicknesses (especially near the 1.5 nm critical thickness) could reveal to what degree (if any) the magnetism is influenced by the presence of a 2DEG. However, as in the crystalline system, isolation of the role of oxygen vacancies from electronic reconstructions remains a challenge.

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